

1.2V to 3.6V, 12-Bit, Nanopower, 4-Wire Micro TOUCH SCREEN CONTROLLER with SPI™

FEATURES

- 4-Wire Touch Screen Interface
- Single 1.2V to 3.6V Supply/Reference
- Ratiometric Conversion
- Effective Throughput Rate:
 - Up to 20kHz (8 Bit) or 10kHz (12 Bit)
- Preprocessing to Reduce Bus Activity
- SPI Interface
- Simple, Command-Based User Interface:
 - **TSC2046** Compatible
 - 8- or 12-Bit Resolution
- On-Chip Temperature Measurement
- Touch Pressure Measurement
- Digital Buffered $\overline{\text{PENIRQ}}$
- On-Chip, Programmable $\overline{\text{PENIRQ}}$ Pullup
- Auto Power-Down Control
- Low Power:
 - 32.4 μ A at 1.2V, Fast Mode, 8.2kHz Eq Rate
 - 43.8 μ A at 1.8V, Fast Mode, 8.2kHz Eq Rate
 - 58.4 μ A at 2.7V, Fast Mode, 8.2kHz Eq Rate
- Software Reset
- Enhanced ESD Protection:
 - $\pm 8\text{kV}$ HBM
 - $\pm 1\text{kV}$ CDM
 - Target $\pm 25\text{kV}$ Air Gap Discharge
 - Target $\pm 15\text{kV}$ Contact Discharge
- 1.5 x 2 WCSP-12 and 4 x 4 QFN-16 Packages

U.S. Patent No. 6246394; other patents pending.

APPLICATIONS

- Cellular Phones
- PDA, GPS, and Media Players
- Portable Instruments
- Point-of-Sale Terminals
- Multiscreen Touch Control

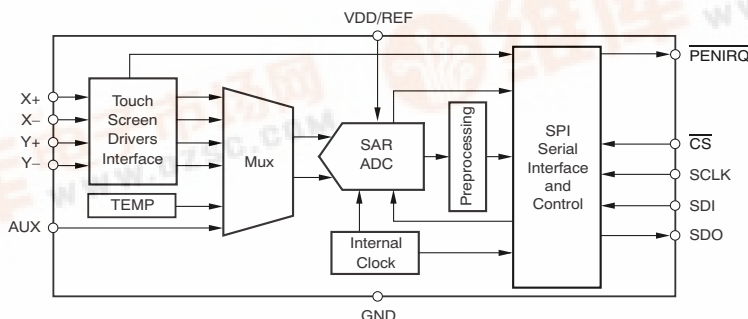
DESCRIPTION

The TSC2008 is a very low-power touch screen controller designed to work with power-sensitive, handheld applications that are based on advanced low-voltage processors. It works with a supply voltage as low as 1.2V, which can be supplied by a single-cell battery. It contains a complete, ultra-low power, 12-bit, analog-to-digital (A/D) resistive touch screen converter, including drivers and the control logic to measure touch pressure.

In addition to these standard features, the TSC2008 offers preprocessing of the touch screen measurements to reduce bus loading, thus reducing the consumption of host processor resources that can then be redirected to more critical functions.

The TSC2008 supports an SPI serial bus and data transmission protocol in all three defined modes: standard, fast, and high-speed. It offers programmable resolution of 8 or 12 bits to accommodate different screen sizes and performance needs.

The TSC2008 is available in a 12-lead, (1,555 \pm 0,055mm) x (2,055 \pm 0,055mm) 3 x 4 array, wafer chip-scale package (WCSP), and a 16-pin, 4 x 4 QFN package. The TSC2008 is characterized for the -40°C to +85°C industrial temperature range.



PRODUCT PREVIEW



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

SPI is a trademark of Motorola Inc.

• All other trademarks are the property of their respective owners.

PRODUCT PREVIEW information concerns products in the formative or design phase of development. Characteristic data and

Copyright © 2008, Texas Instruments Incorporated



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾

PRODUCT	TYPICAL INTEGRAL LINEARITY (LSB)	TYPICAL GAIN ERROR (LSB)	NO MISSING CODES RESOLUTION (BITS)	PACKAGE TYPE	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING	ORDERING NUMBER	TRANSPORT MEDIA, QUANTITY
TSC2008I	±1.5	–0.2/+4.4	11	16-Pin, 4 x 4 QFN	RGV	–40°C to +85°C	TSC2008I	TSC2008RGVT	Small Tape and Reel, 250
								TSC2008RGVR	Tape and Reel, 25000
				12-Pin, 3 x 4 Matrix, 1.5 x 2 WCSP	YZG	–40°C to +85°C	TSC2008I	TSC2008IYZGT	Small Tape and Reel, 250
								TSC2008IYZGR	Tape and Reel, 3000

(1) For the most current package and ordering information, see the Package Option Addendum located at the end of this data sheet, or see the TI website at www.ti.com.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Over operating free-air temperature range (unless otherwise noted).

PARAMETER			TSC2008	UNIT
Voltage	Analog input X+, Y+, AUX to GND		−0.4 to VDD + 0.1	V
	Analog input X−, Y− to GND		−0.4 to VDD + 0.1	V
Voltage range	VDD to GND		−0.3 to +5	V
Digital input voltage to GND			−0.3 to VDD + 0.3	V
Digital output voltage to GND			−0.3 to VDD + 0.3	V
Power dissipation			(T _J Max - T _A)/θ _{JA}	
Thermal impedance, θ _{JA}	QFN package		47	°C/W
	WCSP	Low-K	113	°C/W
		High-K	62	°C/W
Operating free-air temperature range, T _A			−40 to +85	°C
Storage temperature range, T _{STG}			−65 to +150	°C
Junction temperature, T _J Max			+150	°C
Lead temperature	Vapor phase (60 sec)		+215	°C
	Infrared (15 sec)		+220	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated is not implied. Exposure to absolute-maximum rated conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

At $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{DD} = +1.2\text{V}$ to $+3.6\text{V}$, unless otherwise noted.

PARAMETER		TEST CONDITIONS	TSC2008			UNIT
			MIN	TYP	MAX	
AUXILIARY ANALOG INPUT						
Input voltage range			0		V _{DD}	V
Input capacitance				12		pF
Input leakage current			−1		+1	μA
A/D CONVERTER						
Resolution		Programmable: 8 or 12 bits			12	Bits
No missing codes		12-bit resolution	11			Bits
Integral linearity				±1.5		LSB ⁽¹⁾
Offset error		V _{DD} = 1.8V		−0.8 to +0.3		LSB
		V _{DD} = 3.0V		+3.2 to +8.9		LSB
Gain error		V _{DD} = 1.8V		−0.2 to 0		LSB
		V _{DD} = 3.0V		+3.8 to +4.4		LSB
TOUCH SENSORS						
$\overline{\text{PENIRQ}}$ pull-up resistor, R _{IRQ}		T _A = +25°C, V _{DD} = 1.8V, command '1011' set '0000'		51		kΩ
		T _A = +25°C, V _{DD} = 1.8V, command '1011' set '0001'		90		kΩ
Switch on-resistance	Y+, X+			6		Ω
	Y−, X−			5		Ω
Switch drivers drive current ⁽²⁾		100ms duration			50	mA
INTERNAL TEMPERATURE SENSOR						
Temperature range			−40		+85	°C
Resolution	Differential method ⁽³⁾	V _{DD} = 3V		1.6		°C/LSB
		V _{DD} = 1.6V		1.6		°C/LSB
	TEMP1 ⁽⁴⁾	V _{DD} = 3V		0.3		°C/LSB
		V _{DD} = 1.6V		0.3		°C/LSB
Accuracy	Differential method ⁽³⁾	V _{DD} = 3V		±2		°C/LSB
		V _{DD} = 1.6V		±2		°C/LSB
	TEMP1 ⁽⁴⁾	V _{DD} = 3V		±3		°C/LSB
		V _{DD} = 1.6V		±3		°C/LSB
INTERNAL OSCILLATOR						
Internal clock frequency, f _{CLK}	8-Bit	V _{DD} = 1.2V		3.19		MHz
		V _{DD} = 1.8V		3.66		MHz
		V _{DD} = 2.7V		3.78		MHz
		V _{DD} = 3.6V		3.82		MHz
	12-Bit	V _{DD} = 1.2V		1.6		MHz
		V _{DD} = 1.8V		1.83		MHz
		V _{DD} = 2.7V		1.88		MHz
		V _{DD} = 3.6V		1.91		MHz
Frequency drift		V _{DD} = 1.6V		0.0056		%/°C
		V _{DD} = 3.0V		0.012		%/°C

(1) LSB means *least significant bit*. With $V_{DD}(\text{REF}) = +2.5\text{V}$, 1LSB is 610 μV .

(2) Assured by design, but not production tested. Exceeding 50mA source current may result in device degradation.

(3) Difference between TEMP1 and TEMP2 measurement; no calibration necessary.

(4) Temperature drift is –2.1mV/ $^{\circ}\text{C}$.

ELECTRICAL CHARACTERISTICS (continued)

At $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{DD} = +1.2\text{V}$ to $+3.6\text{V}$, unless otherwise noted.

PARAMETER		TEST CONDITIONS		TSC2008			UNIT
				MIN	TYP	MAX	
DIGITAL INPUT/OUTPUT							
Logic family				CMOS			
Logic level	V _{IH}	1.2V ≤ V _{DD} < 1.6V		0.7 × V _{DD}	V _{DD} + 0.3	V	
		1.6V ≤ V _{DD} ≤ 3.6V		0.7 × V _{DD}	V _{DD} + 0.3	V	
	V _{IL}	1.2V ≤ V _{DD} < 1.6V		−0.3	0.2 × V _{DD}	V	
		1.6V ≤ V _{DD} ≤ 3.6V		−0.3	0.3 × V _{DD}	V	
	I _{IL}	CS, SCLK, and SDI pins		−1	1	μA	
	C _{IN}	CS, SCLK, and SDI pins			10	pF	
	V _{OH}	I _{OH} = 2 TTL loads		V _{DD} − 0.2	V _{DD}	V	
	V _{OL}	I _{OL} = 2 TTL loads		0	0.2	V	
	I _{LEAK}	Floating output		−1	1	μA	
C _{OUT}	Floating output			10	pF		
Data format				Straight Binary			
POWER SUPPLY REQUIREMENTS							
Power-supply voltage							
V _{DD}		Specified performance		1.2	3.6	V	
Quiescent supply current (V _{DD} with sensor off)	12-bit f _{SCLK} = 10MHz, f _{ADC} = 1MHz, PD[1:0] = 0,0	V _{DD} = 1.2V	36.4k eq rate	128	190	μA	
			8.2k eq rate	32.4	48	μA	
		V _{DD} = 1.8V	36.4k eq rate	165	240	μA	
			8.2k eq rate	43.8	60	μA	
		V _{DD} = 2.7V	36.4k eq rate	226.2	335	μA	
			8.2k eq rate	63.4	84	μA	
Power-down supply current		CS = 1, SDI = SCLK = 1, PD[1:0] = 0,0		0	0.8	μA	

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TSC2008IRGVR	PREVIEW	QFN	RGV	16	2500	TBD	Call TI	Call TI
TSC2008IRGVT	PREVIEW	QFN	RGV	16	250	TBD	Call TI	Call TI
TSC2008IYZGR	PREVIEW	DSBGA	YZG	12	3000	TBD	Call TI	Call TI
TSC2008IYZGT	PREVIEW	DSBGA	YZG	12	250	TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBsolete: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

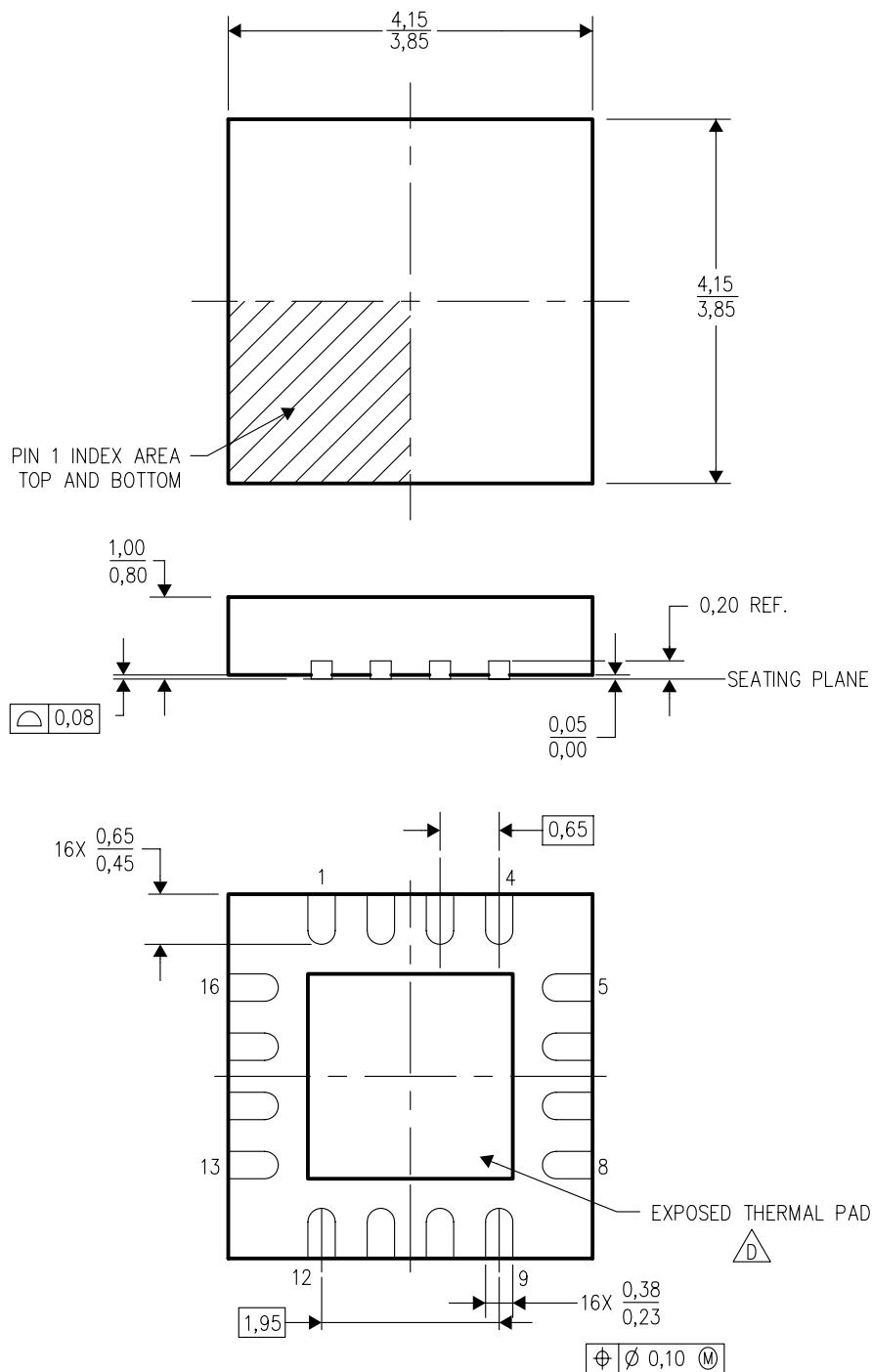
Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.


MECHANICAL DATA

RGV (S-PQFP-N16)

PLASTIC QUAD FLATPACK

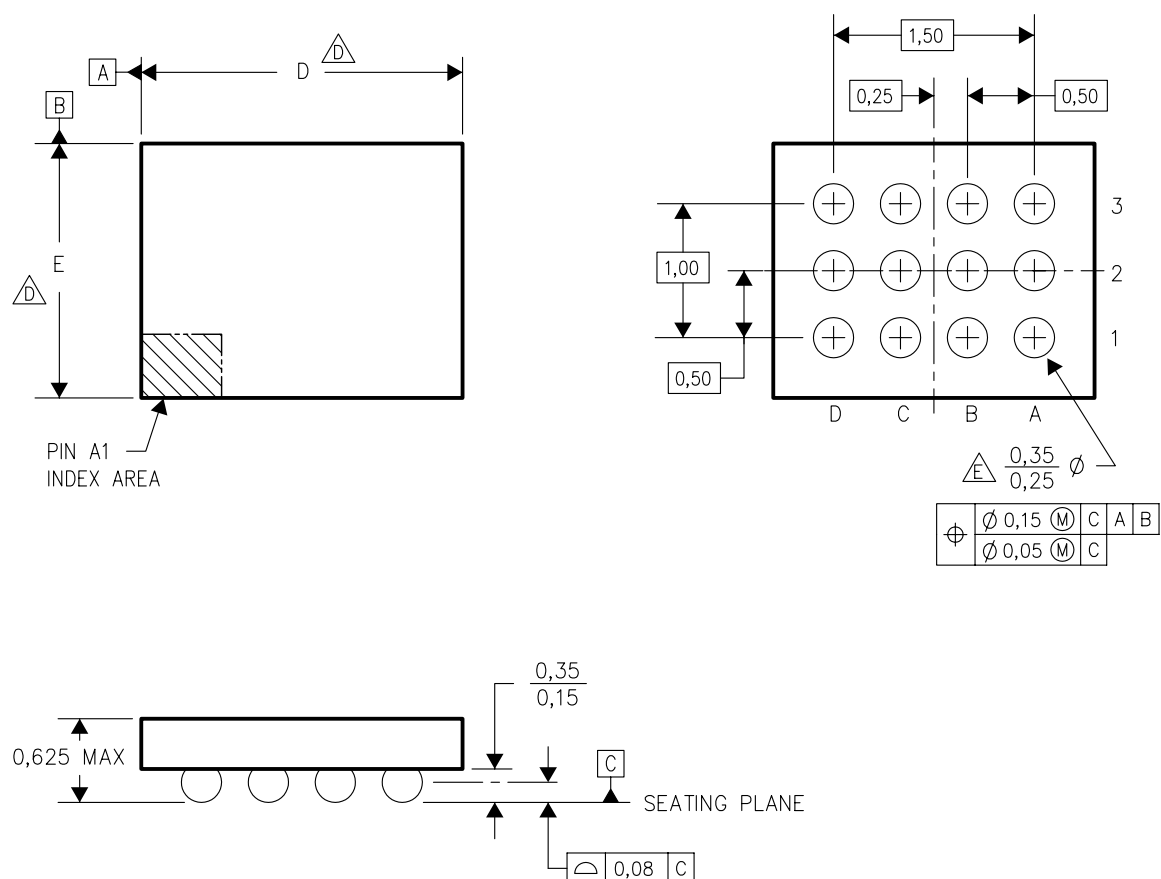


4203497/D 11/04

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Quad Flatpack, No-leads (QFN) package configuration.
 -  The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
 - E. Falls within JEDEC MO-220.

YZG (R-XBGA-N12)

DIE-SIZE BALL GRID ARRAY



4205059/C 05/04

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. NanoFree™ package configuration.
 - D. Devices in YZG package can have dimension D ranging from 1.85 to 2.65 mm and dimension E ranging from 1.35 to 2.15 mm. To determine the exact package size of a particular device, refer to the device datasheet or contact a local TI representative.
 - E. Reference Product Data Sheet for array population. 4 x 3 matrix pattern is shown for illustration only.
 - F. This package contains lead-free balls. Refer to YEG (Drawing #4204182) for tin-lead (SnPb) balls.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products

Amplifiers	amplifier.ti.com
Data Converters	dataconverter.ti.com
DSP	dsp.ti.com
Clocks and Timers	www.ti.com/clocks
Interface	interface.ti.com
Logic	logic.ti.com
Power Mgmt	power.ti.com
Microcontrollers	microcontroller.ti.com
RFID	www.ti-rfid.com
RF/IF and ZigBee® Solutions	www.ti.com/lprf

Applications

Audio	www.ti.com/audio
Automotive	www.ti.com/automotive
Broadband	www.ti.com/broadband
Digital Control	www.ti.com/digitalcontrol
Medical	www.ti.com/medical
Military	www.ti.com/military
Optical Networking	www.ti.com/opticalnetwork
Security	www.ti.com/security
Telephony	www.ti.com/telephony
Video & Imaging	www.ti.com/video
Wireless	www.ti.com/wireless

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2008, Texas Instruments Incorporated